Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.260 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.370 inches
Electrode Internally-electrically Connected To Case:
Collector
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.210 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
-30.0 gate to source voltage all transistor and -30.0 drain to source voltage all transistor
Current Rating Per Characteristic:
-25.00 milliamperes drain cutoff current all transistor and 0.10 milliamperes gate current all transistor
Power Rating Per Characteristic:
112.0 milliwatts total power dissipation all transistor
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Terminal Type And Quantity:
8 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0